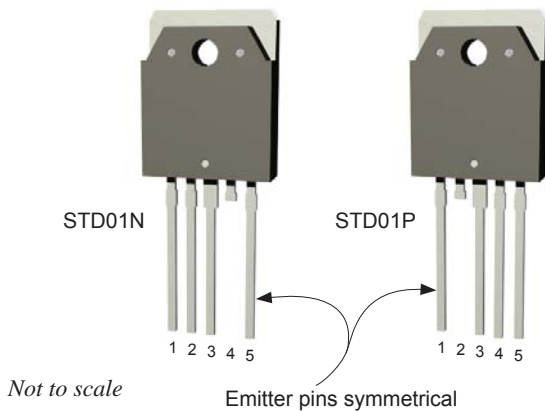


Darlington Transistors for Audio Amplifiers

Features and Benefits

- Built-in temperature compensation diodes
- High power (100 W) handling in a small package (TO-3P), for minimized heat sink requirements
- Built-in drivers and temperature compensation diodes, reducing external component count and simplifying circuit design
- NPN and PNP versions
- Emitter terminals placed symmetrically, pin 5 on NPN and pin 1 on PNP models, allowing adjacent placement on PCB to minimize trace length and output skew when used in pairs
- Approved by major manufacturers

Package: 5-pin TO-3P



Description

The STD01N and STD01P are enhanced Darlington transistors with built-in drivers and temperature compensation diode. Manufactured using the unique SanKen thin-wafer production technology, these devices achieve higher power levels through decreased thermal resistance, and can withstand higher voltages than similar devices on the market.

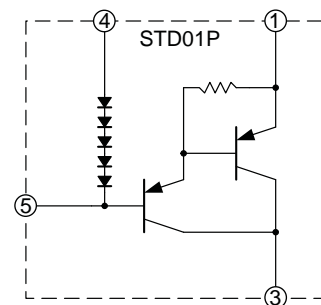
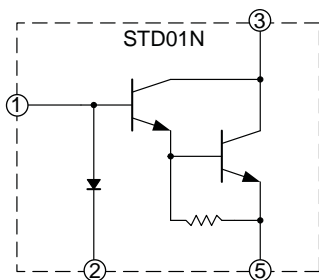
The temperature compensation diode is integrated on the same chip as the power transistors. By this design, the STD01N and STD01P eliminate delays that would otherwise be induced between thermal sensing at the heat source, and the operation of the compensation circuitry. Thus, these transistors are ideal for applications where enhanced thermal stability is required.

This device is provided in a 5-pin TO-3P plastic package with pin 4 removed. Contact Allegro® for application support and additional information on device performance.

Applications include:

- General amplifier applications
- Professional audio amplifiers
- Car audio amplifiers

Equivalent Circuits



SELECTION GUIDE

| Part Number | Type | h _{FE} Rating | Packing |
|-------------|------|------------------------|--------------------|
| STD01N* | NPN | Range O: 5000 to 12000 | 30 pieces per tube |
| | | Range Y: 8000 to 20000 | |
| STD01P* | PNP | Range O: 5000 to 12000 | |
| | | Range Y: 8000 to 20000 | |

*Specify h_{FE} range when ordering. If no h_{FE} range is specified, order will be fulfilled with either or both range O and range Y, depending upon availability.

ABSOLUTE MAXIMUM RATINGS at T_A = 25°C

| Characteristic | Symbol | Rating | Unit |
|--|------------------|------------|------|
| Collector-Base Voltage ¹ | V _{CBO} | 150 | V |
| Collector-Emitter Voltage ¹ | V _{CEO} | 150 | V |
| Emitter-Base Voltage ¹ | V _{EBO} | 5 | V |
| Collector Current ¹ | I _C | 10 | A |
| Base Current ¹ | I _B | 1 | A |
| Collector Power Dissipation ² | P _C | 100 | W |
| Diode Forward Current | I _F | 10 | mA |
| Junction Temperature | T _J | 150 | °C |
| Storage Temperature | T _{stg} | -55 to 150 | °C |

¹For PNP type (STD01P), voltage and current values are negative.

²T_C = 25°C.

ELECTRICAL CHARACTERISTICS at T_A = 25°C

| Characteristic | Symbol | Test Conditions | Min. | Typ. | Max. | Unit |
|---|----------------------|---|------|------|-------|------|
| Collector-Cutoff Current ¹ | I _{CBO} | V _{CB} = 150 V | – | – | 100 | μA |
| Emitter Cutoff Current ¹ | I _{EBO} | V _{EB} = 5 V | – | – | 100 | μA |
| Collector-Emitter Voltage ¹ | V _{CEO} | I _C = 30 mA | 150 | – | – | V |
| DC Current Transfer Ratio ^{2,3} | h _{FE} | V _{CE} = 4 V, I _C = 6 A | 5000 | – | 20000 | – |
| Collector-Emitter Saturation Voltage ¹ | V _{CE(sat)} | I _C = 6 A, I _B = 6 mA | – | – | 2.0 | V |
| Base-Emitter Saturation Voltage ¹ | V _{BE(sat)} | I _C = 6 A, I _B = 6 mA | – | – | 2.5 | V |
| Base-Emitter Voltage | V _{BE} | STD01N V _{CE} = 20 V, I _C = 40 mA | – | 1220 | – | mV |
| | | STD01P V _{CE} = -20 V, I _C = -40 mA | – | 1230 | – | mV |
| Diode Forward Voltage | V _F | STD01N I _F = 2.5 mA | – | 705 | – | mV |
| | | STD01P I _F = 2.5 mA | – | 1580 | – | mV |

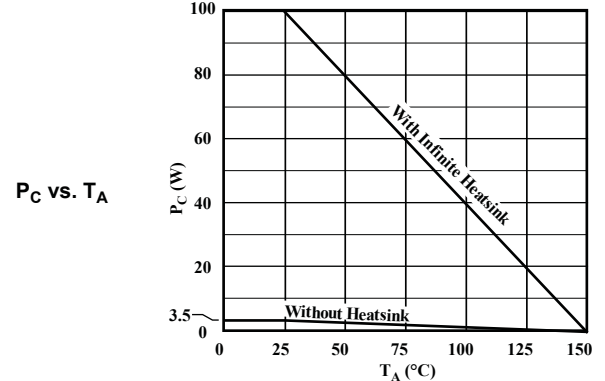
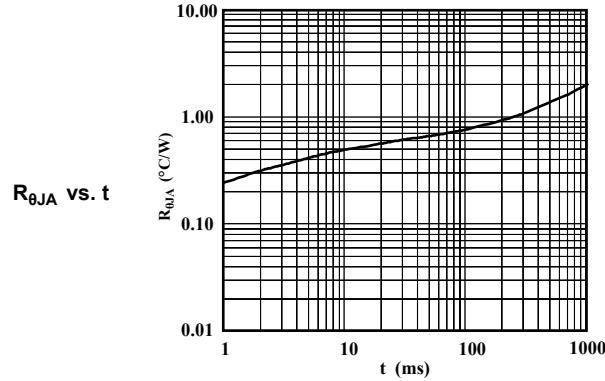
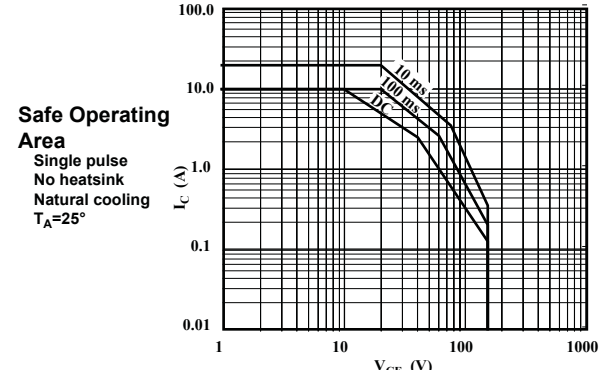
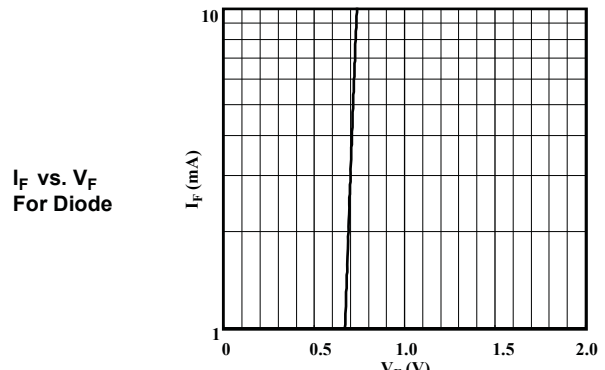
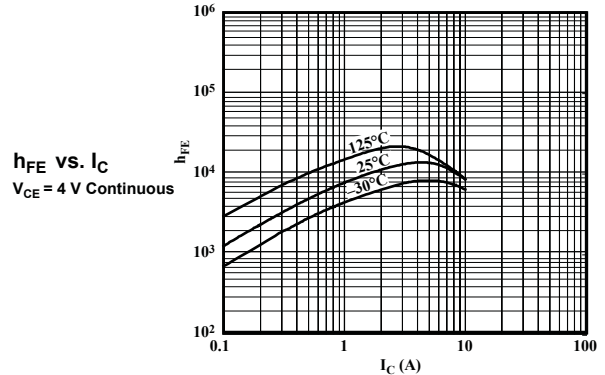
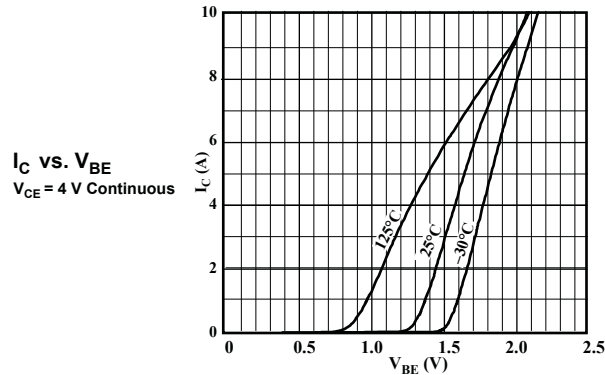
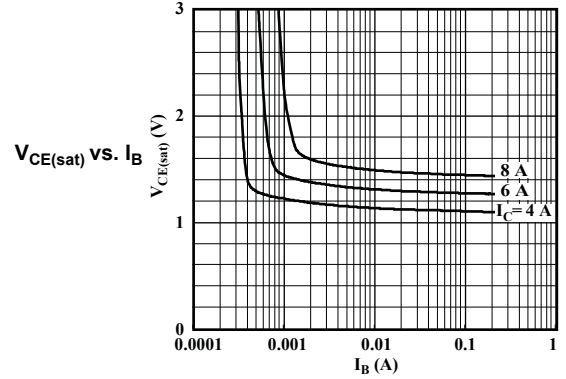
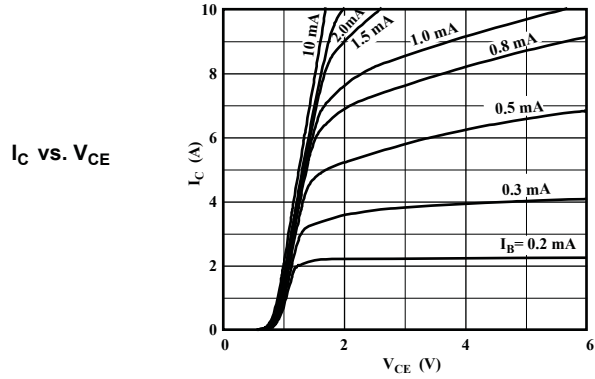
¹For PNP type (STD01P), voltage and current values are negative.

²h_{FE} rating: 5000 to 12000(O brand on package), 8000 to 20000 (Y).

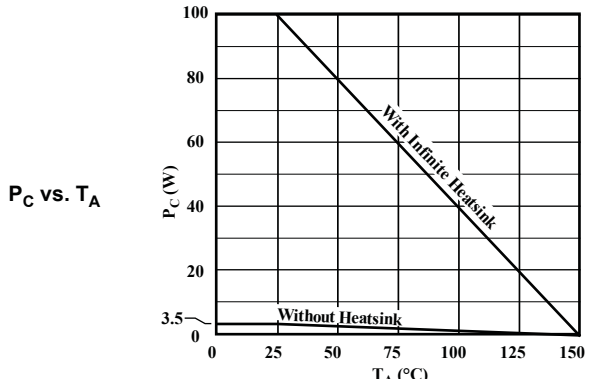
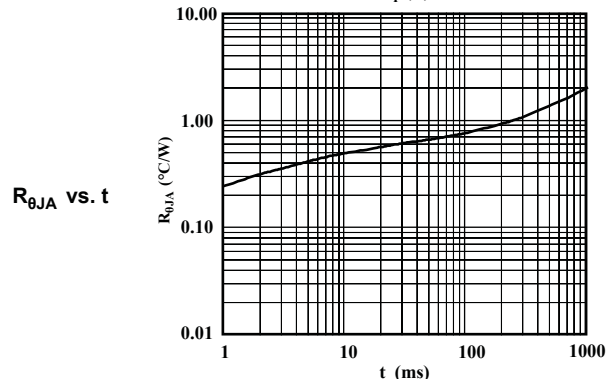
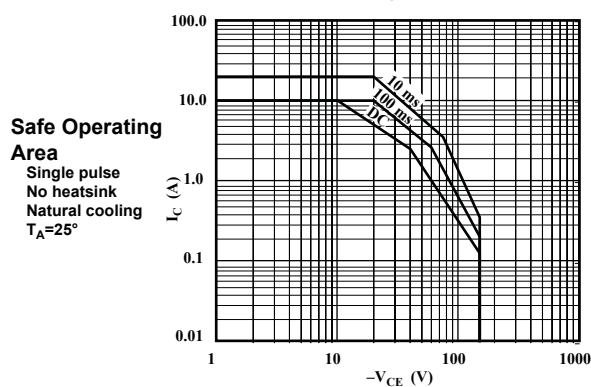
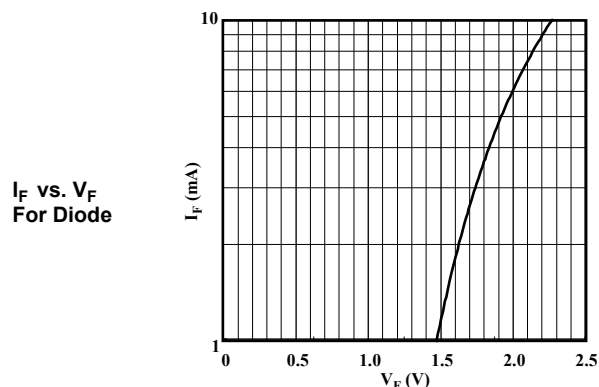
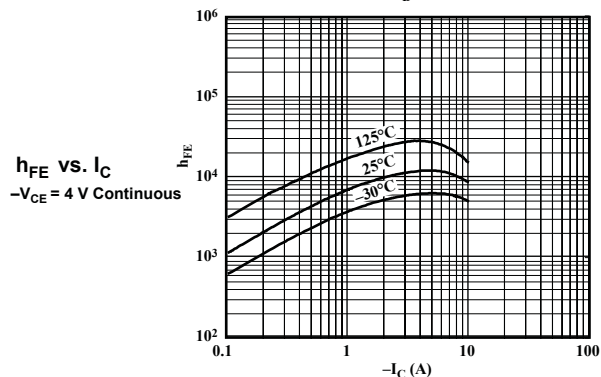
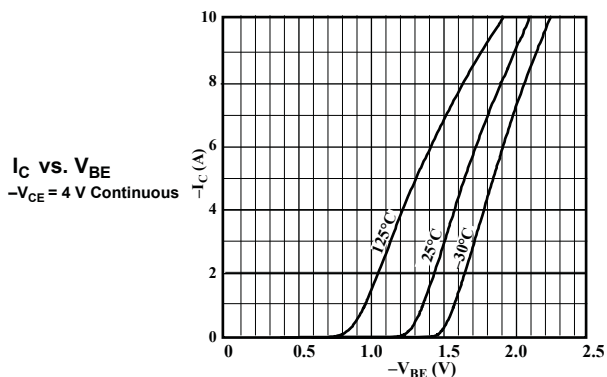
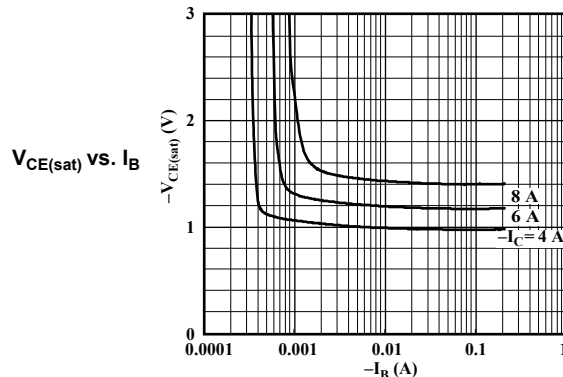
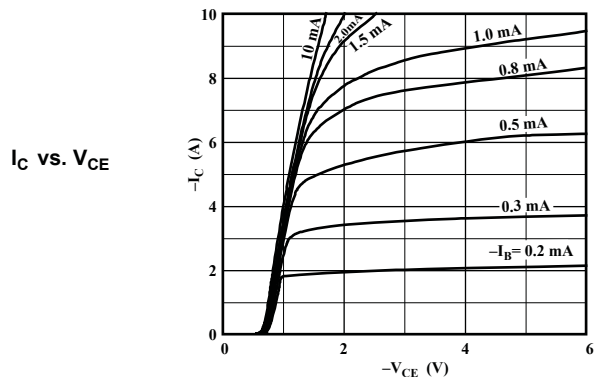
³When the transistor is used in pairs, the following conditions must be satisfied: Total V_F ≤ Total V_{BE} of the transistors (the above measurement conditions shall be applied), and ΔV = 0 to 500 mV.

All performance characteristics given are typical values for circuit or system baseline design only and are at the nominal operating voltage and an ambient temperature of +25°C, unless otherwise stated.

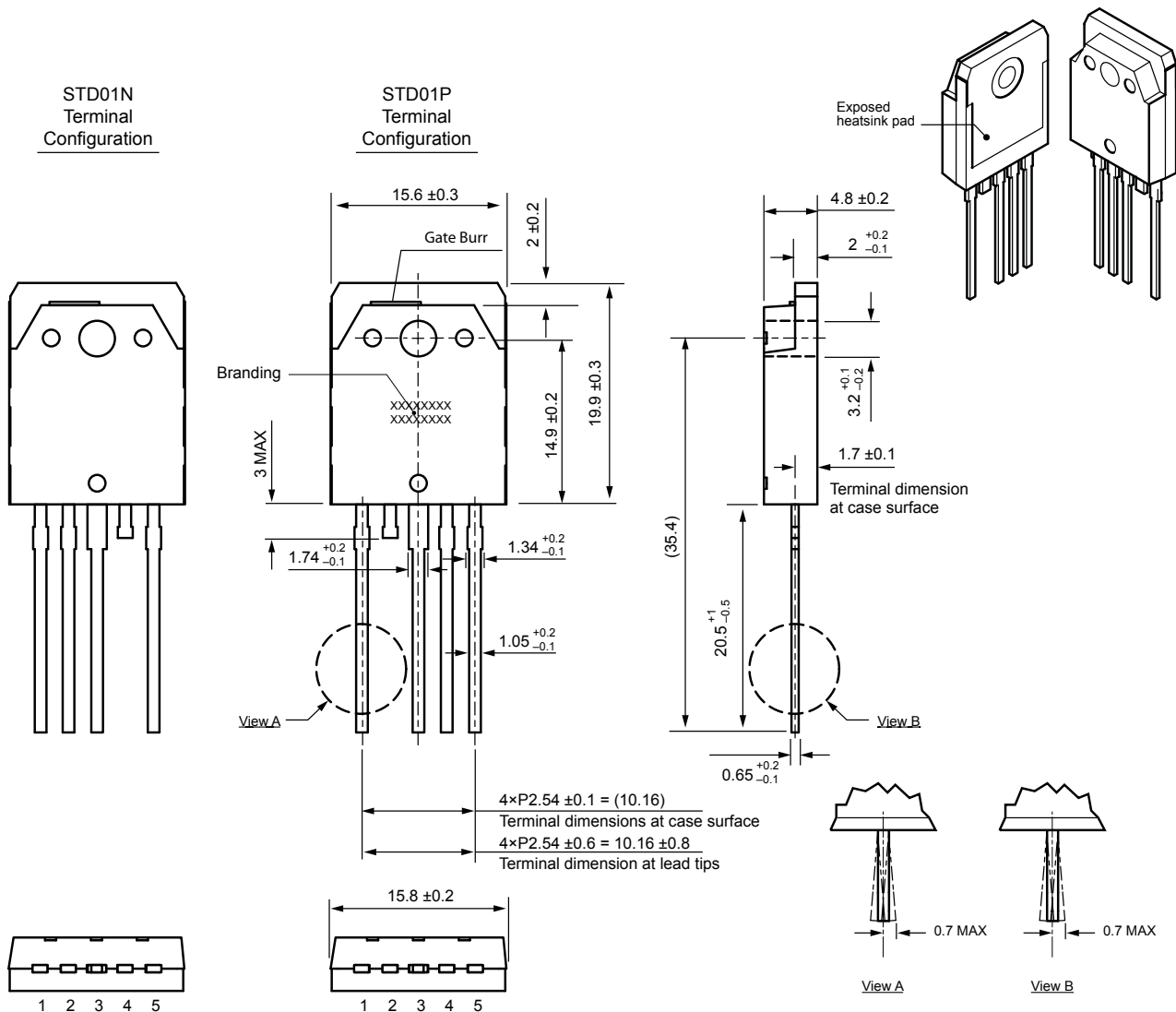
STD01N Performance Characteristics at $T_A = 25^\circ\text{C}$



STD01P Performance Characteristics at $T_A = 25^\circ\text{C}$



Package Outline Drawing, TO-3P



Gate burr: 0.3 mm (max.), mold flash may appear at opposite side
 Terminal core material: Cu
 Terminal treatment: Ni plating and solder dip
 Heat sink material: Cu
 Heat sink treatment: Ni plating
 Leadform: 2804(N), 2803(P)
 Package: TO-3P (MT-100)
 Weight (approximate): 6.0 g

Dimensions in millimeters

Branding codes (exact appearance at manufacturer discretion):
 1st line, type: STD01X
 Where: X is the transistor type (N or P)
 2nd line, lot: YMDD H
 Where: Y is the last digit of the year of manufacture
 M is the month (1 to 9, O, N, D)
 DD is the 2-digit date
 H is the h_{FE} rating (O or Y; for values see footnote, Electrical Characteristics table)



Leadframe plating Pb-free. Device composition includes high-temperature solder (Pb >85%), which is exempted from the RoHS directive.

Because reliability can be affected adversely by improper storage environments and handling methods, please observe the following cautions.

Cautions for Storage

- Ensure that storage conditions comply with the standard temperature (5°C to 35°C) and the standard relative humidity (around 40% to 75%); avoid storage locations that experience extreme changes in temperature or humidity.
- Avoid locations where dust or harmful gases are present and avoid direct sunlight.
- Reinspect for rust on leads and solderability of the products that have been stored for a long time.

Cautions for Testing and Handling

When tests are carried out during inspection testing and other standard test periods, protect the products from power surges from the testing device, shorts between the product pins, and wrong connections. Ensure all test parameters are within the ratings specified by Sanken for the products.

Remarks About Using Silicone Grease with a Heatsink

- When silicone grease is used in mounting the products on a heatsink, it shall be applied evenly and thinly. If more silicone grease than required is applied, it may produce excess stress.
- Volatile-type silicone greases may crack after long periods of time, resulting in reduced heat radiation effect. Silicone greases with low consistency (hard grease) may cause cracks in the mold resin when screwing the products to a heatsink.

Our recommended silicone greases for heat radiation purposes, which will not cause any adverse effect on the product life, are indicated below:

| Type | Suppliers |
|--------|--------------------------------------|
| G746 | Shin-Etsu Chemical Co., Ltd. |
| YG6260 | Momentive Performance Materials Inc. |
| SC102 | Dow Corning Toray Co., Ltd. |

Cautions for Mounting to a Heatsink

- When the flatness around the screw hole is insufficient, such as when mounting the products to a heatsink that has an extruded (burred) screw hole, the products can be damaged, even with a lower than recommended screw torque. For mounting the products, the mounting surface flatness should be 0.05 mm or less.
- Please select suitable screws for the product shape. Do not

use a flat-head machine screw because of the stress to the products. Self-tapping screws are not recommended. When using self-tapping screws, the screw may enter the hole diagonally, not vertically, depending on the conditions of hole before threading or the work situation. That may stress the products and may cause failures.

- Recommended screw torque: 0.686 to 0.882 N•m (7 to 9 kgf•cm).
- Diameter of Heatsink Hole: < 4 mm. The deflection of the press mold when making the hole may cause the case material to crack at the joint with the heatsink. Please pay special attention for this effect.
- For tightening screws, if a tightening tool (such as a driver) hits the products, the package may crack, and internal stress fractures may occur, which shorten the lifetime of the electrical elements and can cause catastrophic failure. Tightening with an air driver makes a substantial impact. In addition, a screw torque higher than the set torque can be applied and the package may be damaged. Therefore, an electric driver is recommended.

When the package is tightened at two or more places, first pre-tighten with a lower torque at all places, then tighten with the specified torque. When using a power driver, torque control is mandatory.

Soldering

- When soldering the products, please be sure to minimize the working time, within the following limits:
 260±5°C 10±1 s (Flow, 2 times)
 350±5°C 3±0.5 s (Soldering iron, 1 time)
- Soldering should be at a distance of at least 1.5 mm from the body of the products.

Electrostatic Discharge

- When handling the products, the operator must be grounded. Grounded wrist straps worn should have at least 1 MΩ of resistance from the operator to ground to prevent shock hazard, and it should be placed near the operator.
- Workbenches where the products are handled should be grounded and be provided with conductive table and floor mats.
- When using measuring equipment such as a curve tracer, the equipment should be grounded.
- When soldering the products, the head of soldering irons or the solder bath must be grounded in order to prevent leak voltages generated by them from being applied to the products.
- The products should always be stored and transported in Sanken shipping containers or conductive containers, or be wrapped in aluminum foil.

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- The contents in this document are subject to changes, for improvement and other purposes, without notice. Make sure that this is the latest revision of the document before use.
 - Application and operation examples described in this document are quoted for the sole purpose of reference for the use of the products herein and Sanken can assume no responsibility for any infringement of industrial property rights, intellectual property rights or any other rights of Sanken or any third party which may result from its use.
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In addition, it should be noted that since power devices or IC's including power devices have large self-heating value, the degree of derating of junction temperature affects the reliability significantly.

- When using the products specified herein by either (i) combining other products or materials therewith or (ii) physically, chemically or otherwise processing or treating the products, please duly consider all possible risks that may result from all such uses in advance and proceed therewith at your own responsibility.
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